NSN 5961-01-188-2596

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-188-2596 **Inclosure Material:** Metal **Overall Length:** 1.253 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.474 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 repetitive peak reverse voltage, peak total value and 40.0 reverse voltage, peak and 48.0 nonrepetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 wire hook Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: